TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

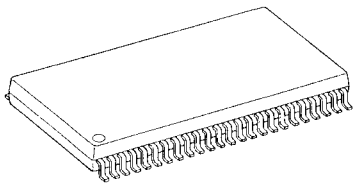
TC74VCXHR162245FT

Low-Voltage 16-Bit Bus Transceiver with Bushold

The TC74VCXHR162245FT is a high-performance CMOS 16-bit bus transceiver. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This 16-bit bus transceiver is controlled by direction control (DIR) inputs and output enable ($\overline{OE}$) inputs which are common to each byte. It can be used as two 8-bit transceivers or one 16-bit transceiver. The direction of data transmission is determined by the level of the DIR inputs. The $\overline{OE}$ inputs can be used to disable the device so that the busses are effectively isolated.

The 26-Ω series resistor helps reducing output overshoot and undershoot without external resistor.



TSSOP48-P-0061-0.50

Weight: 0.25 g (typ.)

The A, B data inputs include active bushold circuitry, eliminating the need for external pull-up resisisors to hold unused or floating data inputs at a valid logic level.

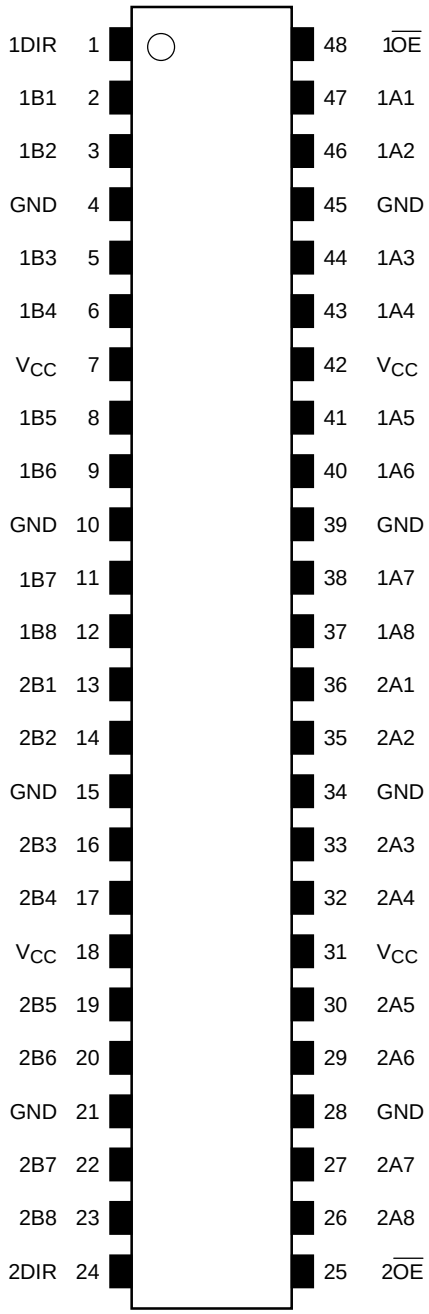
All inputs are equipped with protection circuits against static discharge.

Features

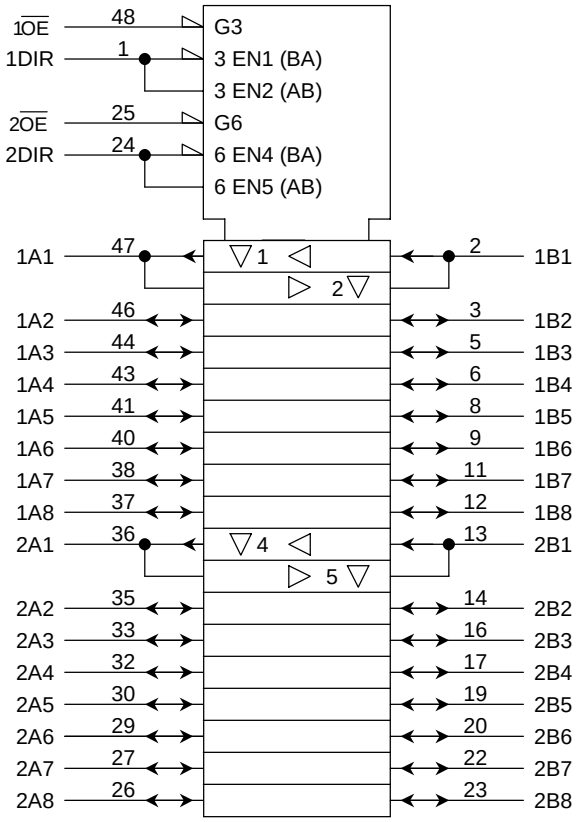
- 26-Ω series resistors on all outputs
- Low-voltage operation: V_{CC} = 1.8 to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation: t_{pd} = 3.4 ns (max) (V_{CC} = 3.0 to 3.6 V)
  : t_{pd} = 4.3 ns (max) (V_{CC} = 2.3 to 2.7 V)
  : t_{pd} = 5.7 ns (max) (V_{CC} = 1.8 V)
- 3.6-V tolerant control inputs.
- Output current: I_{OH}/I_{OL} = ±12 mA (min) (V_{CC} = 3.0 V)
  : I_{OH}/I_{OL} = ±8 mA (min) (V_{CC} = 2.3 V)
  : I_{OH}/I_{OL} = ±4 mA (min) (V_{CC} = 1.8 V)
- Latch-up performance: ±300 mA
- ESD performance: Machine model > ±200 V
  : Human body model > ±2000 V
- Package: TSSOP (thin shrink small outline package)

Note 1: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

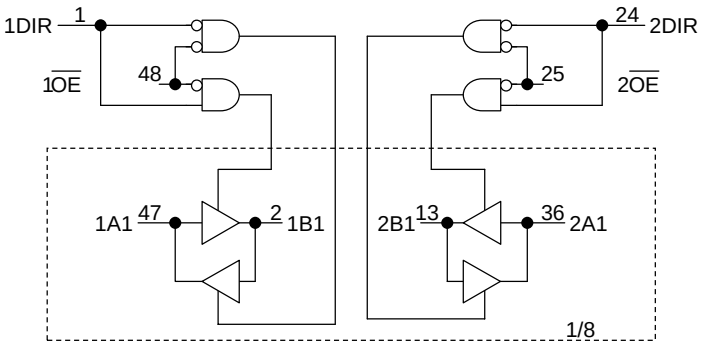
Inputs		Function		Outputs
$1\overline{OE}$	1DIR	Bus 1A1-1A8	Bus 1B1-1B8	
L	L	Output	Input	A = B
L	H	Input	Output	B = A
H	X	Z		Z

Inputs		Function		Outputs
$2\overline{OE}$	2DIR	BUS 2A1-2A8	BUS 2B1-2B8	
L	L	Output	Input	A = B
L	H	Input	Output	B = A
H	X	Z		Z

X: Don’t care

Z: High impedance

System Diagram



Maximum Ratings

Characteristics		Symbol	Rating	Unit
Power supply voltage		V_{CC}	−0.5 to 4.6	V
DC input voltage	(DIR, $\overline{OE}$)	V_{IN}	−0.5 to 4.6	V
	(An, Bn)		−0.5 to V_{CC} + 0.5 (Note 2)	
DC output voltage	(An, Bn)	V_{OUT}	−0.5 to V_{CC} + 0.5 (Note 3)	V
Input diode current		I_{IK}	−50	mA
Output diode current		I_{OK}	±50 (Note 4)	mA
Output current		I_{OUT}	±50	mA
Power dissipation		P_D	400	mW
DC V_{CC}/ground current per supply pin		I_{CC}/I_{GND}	±100	mA
Storage temperature		T_{stg}	−65 to 150	°C

Note 2: OFF state

Note 3: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Recommended Operating Range (Note 5)

Characteristics		Symbol	Rating	Unit
Power supply voltage		V_{CC}	1.8 to 3.6	V
			1.2 to 3.6 (Note 6)	
Input voltage	(DIR, $\overline{OE}$)	V_{IN}	−0.3 to 3.6	V
	(An, Bn)		0 to V_{CC} (Note 7)	
Output voltage	(An, Bn)	V_{OUT}	0 to V_{CC} (Note 8)	V
Output current		I_{OH}/I_{OL}	±12 (Note 9)	mA
			±8 (Note 10)	
			±4 (Note 11)	
Operating temperature		T_{opr}	−40 to 85	°C
Input rise and fall time		dt/dv	0 to 10 (Note 12)	ns/V

Note 5: Floating or unused control inputs must be held high or low.

Note 6: Data retention only

Note 7: OFF state

Note 8: High or low state

Note 9: V_{CC} = 3.0 to 3.6 V

Note 10: V_{CC} = 2.3 to 2.7 V

Note 11: V_{CC} = 1.8 V

Note 12: V_{IN} = 0.8 to 2.0 V, V_{CC} = 3.0 V

Electrical Characteristics

DC Characteristics (Ta = −40 to 85°C, 2.7 V < V_{CC} ≦ 3.6 V)

Characteristics		Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
Input voltage	H-level	V_{IH}	—		2.7 to 3.6	2.0	—	V
	L-level	V_{IL}	—		2.7 to 3.6	—	0.8	
Output voltage	H-level	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −100 μA	2.7 to 3.6	V_{CC} − 0.2	—	V
				I_{OH} = −6 mA	2.7	2.2	—	
				I_{OH} = −8 mA	3.0	2.4	—	
				I_{OH} = −12 mA	3.0	2.2	—	
	L-level	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 100 μA	2.7 to 3.6	—	0.2	
				I_{OL} = 6 mA	2.7	—	0.4	
				I_{OL} = 8 mA	3.0	—	0.5	
				I_{OL} = 12 mA	3.0	—	0.8	
Input leakage current (DIR, $\overline{OE}$)		I_{IN}	V_{IN} = 0 to 3.6 V		2.7 to 3.6	—	±5.0	μA
Bushold input minimum drive hold current		$I_{I (HOLD)}$	V_{IN} = 0.8 V		3.0	75	—	μA
			V_{IN} = 2.0 V		3.0	−75	—	
Bushold input over-drive current to change state		$I_{I (OD)}$	(Note 13)		3.6	—	450	μA
			(Note 14)		3.6	—	−450	
3-state output OFF state current		I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		2.7 to 3.6	—	±10.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		2.7 to 3.6	—	20.0	μA
Increase in I_{CC} per input		ΔI_{CC}	V_{IH} = V_{CC} − 0.6 V		2.7 to 3.6	—	750	μA

Note 13: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 14: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

DC Characteristics (Ta = –40 to 85°C, 2.3 V ≦ V_{CC} ≦ 2.7 V)

Characteristics		Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
Input voltage	H-level	V_{IH}	—		2.3 to 2.7	1.6	—	V
	L-level	V_{IL}	—		2.3 to 2.7	—	0.7	
Output voltage	H-level	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = –100 μA	2.3 to 2.7	V_{CC} – 0.2	—	V
				I_{OH} = –4 mA	2.3	2.0	—	
				I_{OH} = –6 mA	2.3	1.8	—	
				I_{OH} = –8 mA	2.3	1.7	—	
	L-level	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 100 μA	2.3 to 2.7	—	0.2	
				I_{OL} = 6 mA	2.3	—	0.4	
				I_{OL} = 8 mA	2.3	—	0.6	
Input leakage current (DIR, $\overline{OE}$)		I_{IN}	V_{IN} = 0 to 3.6 V		2.3 to 2.7	—	±5.0	μA
Bushold input minimum drive hold current		$I_{I (HOLD)}$	V_{IN} = 0.7 V		2.3	45	—	μA
			V_{IN} = 1.6 V		2.3	–45	—	
Bushold input over-drive current to change state		$I_{I (OD)}$	(Note 13)		2.7	—	300	μA
			(Note 14)		2.7	—	–300	
3-state output OFF state current		I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		2.3 to 2.7	—	±10.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		2.3 to 2.7	—	20.0	μA

Note 13: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 14: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

DC Characteristics (Ta = –40 to 85°C, 1.8 V ≦ V_{CC} < 2.3 V)

Characteristics		Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
Input voltage	H-level	V_{IH}	—		1.8 to 2.3	0.7 × V_{CC}	—	V
	L-level	V_{IL}	—		1.8 to 2.3	—	0.2 × V_{CC}	
Output voltage	H-level	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = –100 μA	1.8	V_{CC} – 0.2	—	V
				I_{OH} = –4 mA	1.8	1.4	—	
	L-level	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 100 μA	1.8	—	0.2	
				I_{OL} = 4 mA	1.8	—	0.3	
Input leakage current (DIR, $\overline{OE}$)		I_{IN}	V_{IN} = 0 to 3.6 V		1.8	—	±5.0	μA
Bushold input minimum drive hold current		$I_{I (HOLD)}$	V_{IN} = 0.36 V		1.8	25	—	μA
			V_{IN} = 1.26 V		1.8	–25	—	
Bushold input over-drive current to change state		$I_{I (OD)}$	(Note 13)		1.8	—	200	μA
			(Note 14)		1.8	—	–200	
3-state output OFF state current		I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		1.8	—	±10.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		1.8	—	20.0	μA

Note 13: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 14: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

AC Characteristics (Ta = –40 to 85°C, input: t_r = t_f = 2.0 ns, C_L = 30 pF, R_L = 500 Ω)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Min	Max	Unit
Propagation delay time	t_{pLH} t_{pHL}	Figure 1, Figure 2	1.8	1.5	5.7	ns
			2.5 ± 0.2	1.0	4.3	
			3.3 ± 0.3	0.8	3.4	
3-state output enable time	t_{pZL} t_{pZH}	Figure 1, Figure 3	1.8	1.5	7.6	ns
			2.5 ± 0.2	1.0	5.7	
			3.3 ± 0.3	0.8	4.2	
3-state output disable time	t_{pLZ} t_{pHZ}	Figure 1, Figure 3	1.8	1.5	5.7	ns
			2.5 ± 0.2	1.0	4.8	
			3.3 ± 0.3	0.8	4.1	
Output to output skew	t_{osLH} t_{osHL}	(Note 15)	1.8	—	0.5	ns
			2.5 ± 0.2	—	0.5	
			3.3 ± 0.3	—	0.5	

For C_L = 50 pF, add approximately 300 ps to the AC maximum specification.

Note 15: Parameter guaranteed by design.
(t_{osLH} = $|t_{pLHm} - t_{pLHn}|$, t_{osHL} = $|t_{pHLm} - t_{pHLn}|$)

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Typ.	Unit
Quiet output maximum dynamic V_{OL}	V_{OLP}	V_{IH} = 1.8 V, V_{IL} = 0 V (Note 16)	1.8	0.15	V
		V_{IH} = 2.5 V, V_{IL} = 0 V (Note 16)	2.5	0.25	
		V_{IH} = 3.3 V, V_{IL} = 0 V (Note 16)	3.3	0.35	
Quiet output minimum dynamic V_{OL}	V_{OLV}	V_{IH} = 1.8 V, V_{IL} = 0 V (Note 16)	1.8	−0.15	V
		V_{IH} = 2.5 V, V_{IL} = 0 V (Note 16)	2.5	−0.25	
		V_{IH} = 3.3 V, V_{IL} = 0 V (Note 16)	3.3	−0.35	
Quiet output minimum dynamic V_{OH}	V_{OHV}	V_{IH} = 1.8 V, V_{IL} = 0 V (Note 16)	1.8	1.55	V
		V_{IH} = 2.5 V, V_{IL} = 0 V (Note 16)	2.5	2.05	
		V_{IH} = 3.3 V, V_{IL} = 0 V (Note 16)	3.3	2.65	

Note 16: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

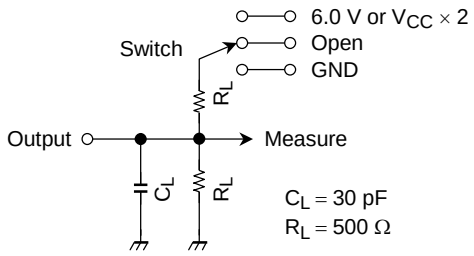
Characteristics	Symbol	Test Condition	V_{CC} (V)	Typ.	Unit
Input capacitance	C_{IN}	—	1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	$C_{I/O}$	—	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C_{PD}	f_{IN} = 10 MHz (Note 17)	1.8, 2.5, 3.3	20	pF

Note 17: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16$ (per bit)

AC Test Circuit



Parameter	Switch	
t_{pLH}, t_{pHL}	Open	
t_{pLZ}, t_{pZL}	6.0 V $V_{CC} \times 2$	@V_{CC} = 3.3 ± 0.3 V @V_{CC} = 2.5 ± 0.2 V @V_{CC} = 1.8 V
t_{pHZ}, t_{pZH}	GND	

Figure 1

AC Waveform

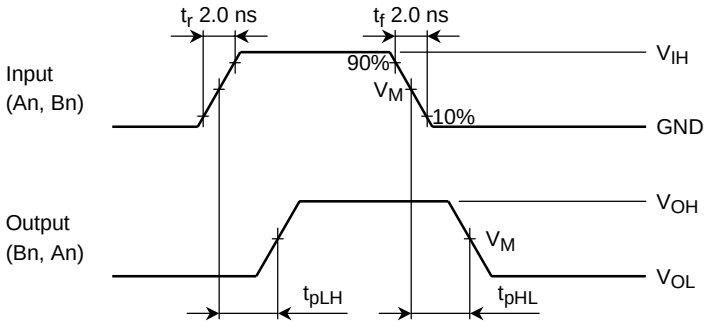


Figure 2 t_{pLH}, t_{pHL}

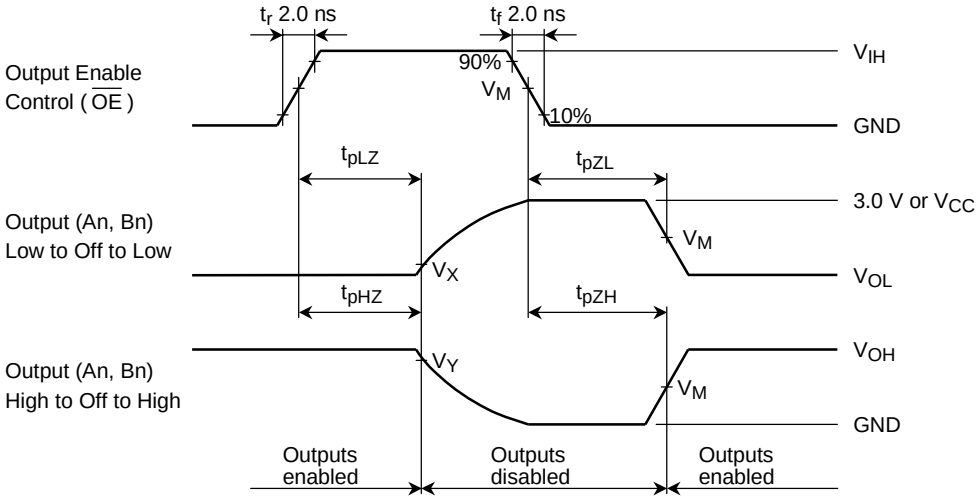
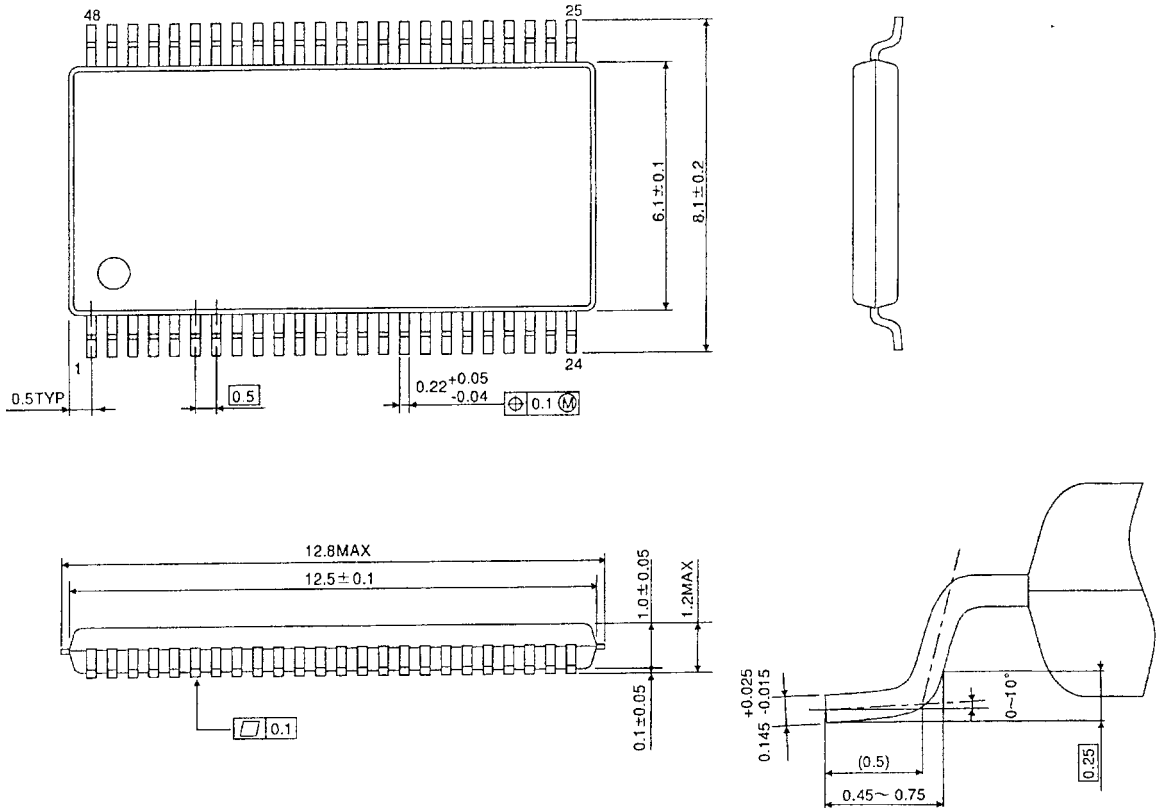


Figure 3 t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}

Symbol	V_{CC}		
	3.3 ± 0.3 V	2.5 ± 0.2 V	1.8 V
V_{IH}	2.7 V	V_{CC}	V_{CC}
V_M	1.5 V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} + 0.3 V	V_{OL} + 0.15 V	V_{OL} + 0.15 V
V_Y	V_{OH} − 0.3 V	V_{OH} − 0.15 V	V_{OH} − 0.15 V

Package Dimensions

TSSOP48-P-0061-0.50 Unit : mm



Weight: 0.25 g (typ.)

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000707EBA

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